



Frequency Generator for Multimedia Audio Synthesis

General Description

The ICS9120-51 is a high performance frequency generator. The ICS9120-51 provides high accuracy; low jitter PLLs meet the 0.20% frequency tolerance and -96dB signal-to-noise ratios. Fast output clock edge rates minimize board induced jitter.

Features

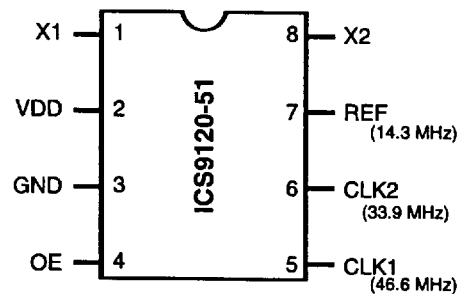
- Generates 46.6 MHz and 33.868 MHz clocks
- Buffered REFCLK output
- 0.20% frequency accuracy
- 100ps one sigma jitter maintains 16-bit performance
- Output rise/fall times less than 2.5ns
- On-chip loop filter components
- 3.0V - 5.5V supply range
- 8-pin, 150-mil SOIC package

Functionality

X1 (MHz)	OE	33.9 (MHz)	46.6 (MHz)	14.3 (MHz)
-	0	Low	Low	Low
14.318	1	33.868	46.6	14.318

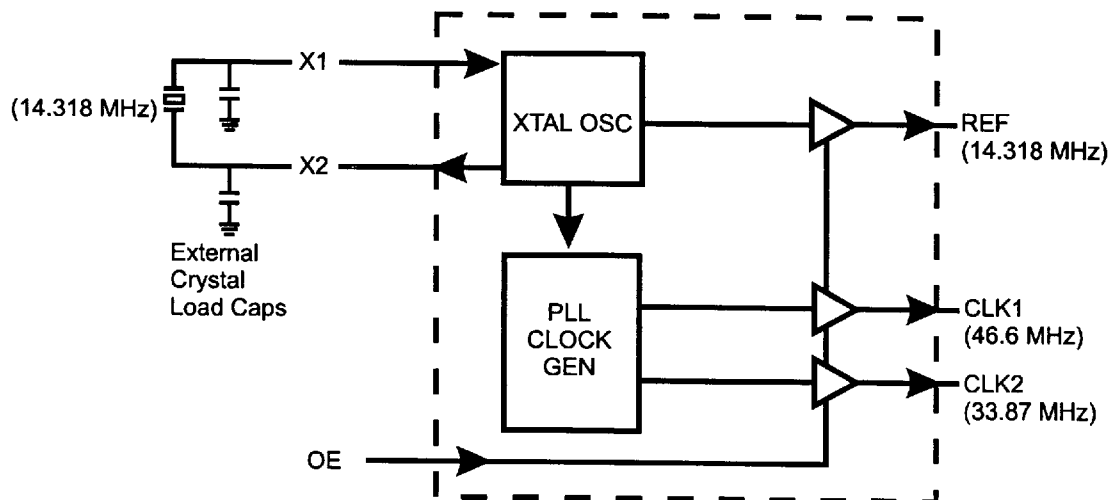
Note: OE (Pin 4) is internally pulled-up to VDD and therefore may be left disconnected or driven by open collector logic. An external pull-up resistor connection is recommended practice.

Pin Configuration



8-Pin SOIC

Block Diagram



ICS9120-51



Pin Descriptions for ICS9120-51

PIN NUMBER	PIN NAME	TYPE	DESCRIPTION
1	X1	Input	Crystal or external clock source. Has feedback bias to crystal*
2	VDD	Power	+Power supply input.
3	GND	Power	Ground return for Pin 2.
4	OE	Input	Output Enable (tristates all outputs when at logic low level); has pull-up.
5	CLK1	Input	46.6 MHz clock output (with nominal 14.318 MHz input).
6	CLK2	Output	33.9 MHz clock output (with nominal 14.318 MHz input).
7	REF	Output	14.318 MHz reference clock output.
8	X2	Output	Crystal output drive (leave this pin unconnected when using an external clock).*

* Contains no internal loading capacitor. External load cap must be connected to ground for crystal oscillator.



Absolute Maximum Ratings

AVDD, VDD referenced to GND 7V
 Operating temperature under bias 0°C to +70°C
 Storage temperature -65°C to +150°C
 Voltage on I/O pins referenced to GND GND -0.5V to VDD +0.5V
 Power dissipation 0.5 Watts

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operation sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect product reliability.

Electrical Characteristics at 5 V

V_{DD} = +4.5 to +5.5 V, T_A = 0 to 70°C unless otherwise stated

DC Characteristics						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Input Low Voltage	VIL		-	-	0.8	V
Input High Voltage	VIH		2.0	-	-	V
Input Low Current	IIL	VIN=0V	-18.0	-8.3	-	mA
Input High Current	IIH	VIN=VDD	-	-	5.0	mA
Output Low Voltage	VOL*	IOL=+10mA	-	0.15	0.4	V
Output High Voltage	VOH*	IOH=-30mA	2.4	3.7	-	V
Output Low Current	IOL*	VOL=0.8V	25.0	45.0	-	mA
Output High Current	IOH*	VOH=2.4V	-	-53.0	-35.0	mA
Supply Current	ICC	Unloaded	-	23.0	50.0	mA
Supply Current, Power-down	ICC(PD)	Unloaded	-	250.0	500.0	mA
Pull-up Resistor Value	Rpu*		-	400.0	800.0	k ohm
AC Characteristics						
Rise Time 0.8 to 2.0V	Tr*	15pF load	-	0.9	2.0	ns
Fall Time 2.0 to 0.8V	Tf*	15pF load	-	0.7	1.5	ns
Rise Time 20% to 80%	Tr*	15pF load	-	1.8	3.25	ns
Fall Time 80% to 20%	Tf*	15pF load	-	1.4	2.5	ns
Duty Cycle	Dt*	15pF load @ 50% of VDD; Except REFCLK	45.0	50.0	55.0	%
Duty Cycle	Dt*	15pF load @ 50% of VDD; REFCLK only	40.0	53.0	60.0	%
Jitter# One Sigma	Tjis*	For all frequencies except REFCLK	-	100.0	150.0	ps
Jitter# Absolute	Tjab*	For all frequencies except REFCLK	-550.0	330.0	550.0	ps
Jitter# One Sigma	Tjis*	REFCLK only	-	350.0	500.0	ps
Jitter# Absolute	Tjab*	REFCLK only	-1200	750.0	1200	ps
Input Frequency	Fi*		11.0	14.0	17.0	MHz
Output Frequency	Fo*		11.0	-	57.0	MHz
Power-up Time	Tpu*	0 to 33.8 MHz	-	5.5	12.0	ms
Crystal Input Capacitance	Cinx*	X1, X2 (Pins 1, 8)	-	5	-	pF

*Parameter is guaranteed by design and characterization. Not 100% tested in production.

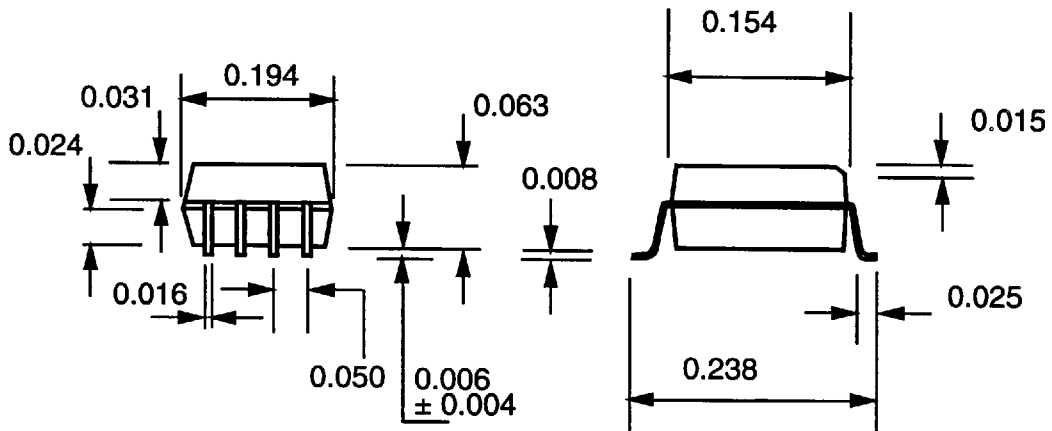


Electrical Characteristics at 3.3 V

$V_{DD} = +3.0$ to $+3.7V$, $T_A = 0^{\circ}C$ - $70^{\circ}C$ unless otherwise stated

DC Characteristics						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Input Low Voltage	V_{IL}		-	-	$0.2V_{DD}$	V
Input High Voltage	V_{IH}		$0.7V_{DD}$	-	-	V
Input Low Current	I_{IL}	$V_{IN}=0V$	-8.0	-3.6	-	μA
Input High Current	I_{IH}	$V_{IN}=V_{DD}$	-	-	5.0	μA
Output Low Voltage	V_{OL}^*	$I_{OL}=6.0mA$	-	$0.05V_{DD}$	0.1	V
Output High Voltage	V_{OH}^*	$I_{OH}=4.0mA$	$0.85V_{DD}$	$0.94V_{DD}$	-	V
Output Low Current	I_{OL}^*	$V_{OL}=0.2V_{DD}$	15.0	24.0	-	mA
Output High Current	I_{OH}^*	$V_{OH}=0.7V_{DD}$	-	-13.0	-8.0	mA
Supply Current	I_{DD}	Unloaded	-	14.0	32.0	mA
Supply Current, Power-down	$I_{CC}(PD)$	Unloaded	-	60.0	110.0	μA
Pull-up Resistor Value	R_{PU}^*		-	620.0	900.0	k ohm
AC Characteristics						
Rise Time	T_r^*	15pF 0.8 to 2.0V	-	1.5	3.5	ns
Fall Time	T_f^*	15pF load 2.0 to 0.8V	-	1.0	2.5	ns
Rise Time	T_r^*	15pF load 20% to 80%	-	2.2	4.0	ns
Fall Time	T_f^*	15pF load 80% to 20%	-	1.5	3.0	ns
Duty Cycle	D_t^*	15pF load @ 50% of V_{DD} ; Except REFCLK	45.0	50.0	55.0	%
Duty Cycle	D_t^*	15pF load @ 50% of V_{DD} ; REFCLK only	40.0	45.0	60.0	%
Jitter, One Sigma	T_{j1s}^*	For all frequencies except REFCLK	-	140.0	200	ps
Jitter Absolute	T_{jab}^*	For all frequencies except REFCLK	-600.0	420.0	600.0	ps
Jitter, One Sigma	T_{j1s}^*	REFCLK only	-	230.0	400.0	ps
Jitter, Absolute	T_{jab}^*	REFCLK only	-1000	600.0	1000	ns
Input Frequency Range	F_i^*		11.0	14.3	15.0	MHz
Output Frequency Range	F_o^*		11.0	-	57.0	MHz
Power-up Time	T_{pu}^*	0 to 33.8 MHz	-	5.5	12.0	ms
Crystal Input Capacitance	C_{inx}^*	X1 (Pin 1), X2 (Pin 8)	-	5	-	pF

*Parameter is guaranteed by design and characterization. Not 100% tested in production.



8-Pin SOIC Package

Ordering Information

ICS9120M-51

Example:

ICS XXXX M-PPP

